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ON Semiconductor®

FDBL86566-F085

N-Channel PowerTrench[®] MOSFET 60 V, 240 A, 2.4 m Ω

Features

- Typical $R_{DS(on)}$ = 1.9 m Ω at V_{GS} = 10V, I_D = 80 A
- Typical Q_{g(tot)} = 80 nC at V_{GS} = 10V, I_D = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain-to-Source Voltage		60	V	
V _{GS}	Gate-to-Source Voltage		±20	V	
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	240		
	Pulsed Drain Current	T _C = 25°C	See Figure 4	— A	
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	193	mJ	
P _D	Power Dissipation		300	W	
	Derate Above 25°C		2.0	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case		0.5	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

- 1: Current is limited by silicon.
- 2: Starting $T_J = 25^{\circ}$ C, $L = 50 \mu$ H, $I_{AS} = 88$ A, $V_{DD} = 60$ V during inductor charging and $V_{DD} = 0$ V during time in avalanche.

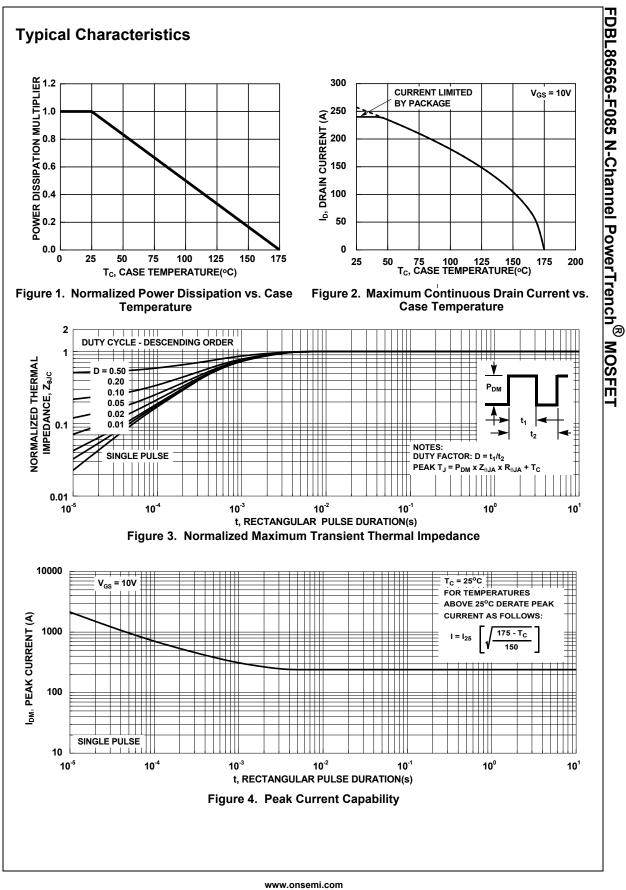
ROHS

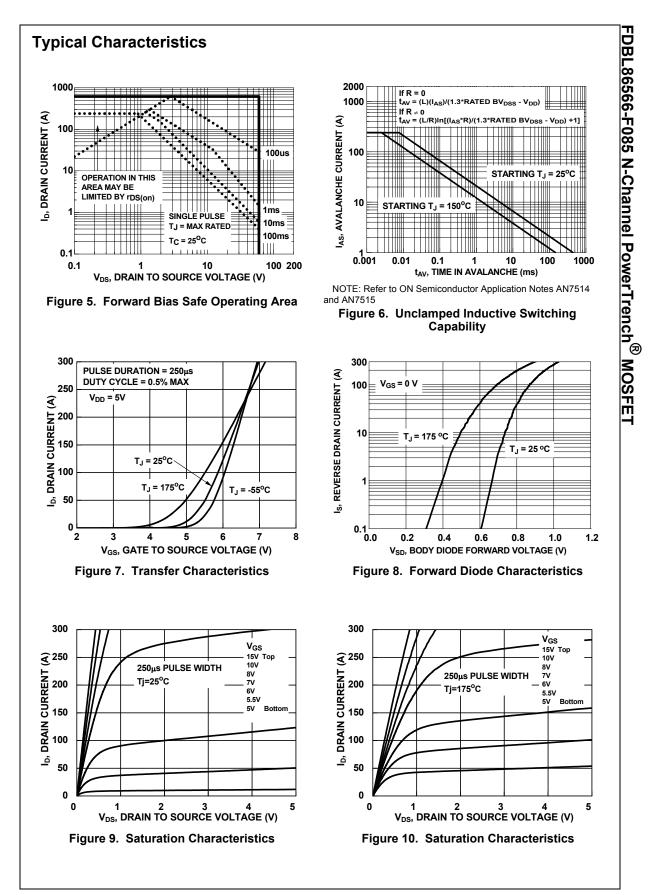
3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

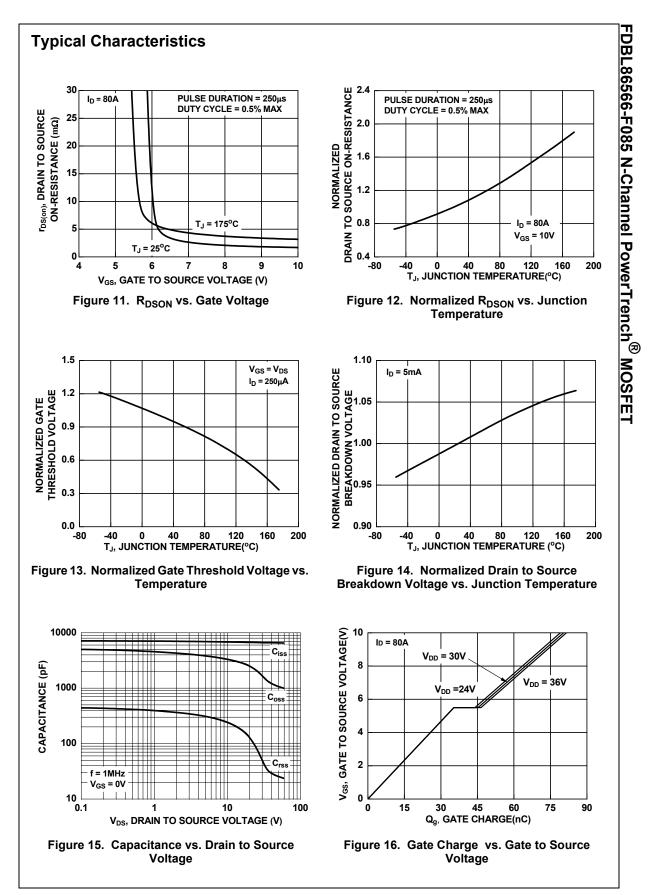
Device Marking	Device	Package	Reel Size	Tape Width	Quantity		
FDBL86566	FDBL86566-F085	MO-299A	13"	24mm	2000 units		

Symbol	Parameter	Test Conditions			Min.	Тур.	Max.	Units
Off Cha	racteristics	·						
B_{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V			60	-	-	V
_	Drain-to-Source Leakage Current	V_{DS} =60V, T_{J} = 25°C			-	-	1	μA
I _{DSS}		$V_{GS} = 0V$	$T_{\rm J} = 17$	5 ^o C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA	
On Cha	racteristics							
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA		2.0	3.2	4.0	V	
		$I_{\rm D} = 80$ A, $T_{\rm J} = 25^{\circ}$ C			-	1.9	2.4	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	$T_{\rm J} = 17$	′5 ^o C (Note 4)	-	3.5	4.5	mΩ
Dynami	ic Characteristics							
C _{iss}	Input Capacitance	V _{DS} = 30V, V _{GS} = 0V, f = 1MHz		-	6655	-	pF	
C _{oss}	Output Capacitance			-	1745	-	pF	
C _{rss}	Reverse Transfer Capacitance			-	57	-	pF	
R _q	Gate Resistance	f = 1MHz		-	2.2	-	Ω	
Q _{g(ToT)}	Total Gate Charge at 10V	V_{GS} = 0 to 10V V_{DD} = 30V		-	80	110	nC	
Q _{g(th)}	Threshold Gate Charge	$V_{GS} = 0 \text{ to } 2V$ $I_D = 80A$		-	12	-	nC	
Q _{gs}	Gate-to-Source Gate Charge				-	35	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	10	-	nC	
Switchi	ng Characteristics							
t _{on}	Turn-On Time				-	-	86	ns
t _{d(on)}	Turn-On Delay				-	37	-	ns
t _r	Rise Time	V_{DD} = 30V, I _D = 80A, V_{GS} = 10V, R _{GEN} = 6Ω		-	29	-	ns	
t _{d(off)}	Turn-Off Delay			-	39	-	ns	
t _f	Fall Time			-	13	-	ns	
t _{off}	Turn-Off Time				-	-	68	ns
Drain-S	ource Diode Characteristics							
V _{SD}	Source-to-Drain Diode Voltage	$I_{SD} = 80A, V_{GS} = 0V$ $I_{SD} = 40A, V_{GS} = 0V$			-	-	1.25	V
				-	-	1.2	V	
t _{rr}	Reverse-Recovery Time	$I_{F} = 80A, dI_{SD}/dt = 100A/\mu s, V_{DD}=48V$		-	78	102	ns	
Q _{rr}	Reverse-Recovery Charge			-	100	130	nC	





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